	Type Hits	Search Text		DBs		Time S
1	BRS 7	((aluminum adj nitride) and (aluminum adj oxide)) with gate	USPA"	Т		2002/06
	BRS 10	((aluminum adi nitride) and (aluminum adi oxide)) with gate	USPA"	T; US-PGPUB		2002/06
	BRS 0	((aluminum adj nitride) and (aluminum adj oxide)) with gate	EPO;	PO; DERWE	IT; IBM_TDB	2002/08
	BRS 1	((aluminum adi nitride) and (aluminum adi oxide)) same gate	EPO:	PO: DERWE	IT: IBM_TDB	2002/06
	BRS 13	((aluminum adj nitride) and (aluminum adj oxide)) and (((high adj dielectric adj constant) or (high with permittivi	USPA'	T; US-PGPUB		2002/0
6	BRS 2	(((aluminum adj nitride) and (aluminum adj oxide)) and (((high adj dielectric adj constant) or (high with permittiv	USPA"	T; US-PGPUB		2002/0
7	BRS 0	((aluminum adj nitride) and (aluminum adj oxide)) and (((high adj dielectric adj constant) or (high with permittivi	EPO;	IPO; DERWE	IT; IBM_TDE	2002/0
8	BRS 10	((ain) and (ai.sub.2 o.sub.3") with gate	USPA"			2002/0
9	BRS 30	(((aln) and ("al.sub.2 o.sub.3")) same gate) not (((aln) and ("al.sub.2 o.sub.3")) with gate)	USPA"	T; US-PGPUB		2002/0
	BRS 0	((ain) and (ai2o3")) with gate	EPO;	IPO; DERWE	IT; IBM_TDB	2002/0
11	BRS 2	((ain) and ("al2o3")) same gate		JPO; DERWE		
	BRS 6	((ain) and (ai2o3))and gate	EPO;	JPO; DERWE	IT; IBM_TDB	2002/0
	BRS 1		USPA	T	······	2002/0
	BRS 0	((aluminum adj nitride) and (aluminum adj oxide)) and "4257832"	USPA"	Ť		2002/0
	BRS 1	((ain) and ("al.sub.2 o.sub.3")) and "4257832"	USPA	T		2002/0
	BRS 1	*6407435*	USPA	T		2002/0
	BRS 1	*4151537" PN	USPA'	T		2002/0
	BRS 1	*4335391* PN.	USPA	T		2002/0
	BRS 1	"6013553" PN.	USPA'	Ť		2002/0
	BRS 1	"6015739" PN	USPA		• • • • • • • • • • • • • • • • • • • •	2002/0
	BRS 1	*6297539*.PN.	USPA		•••••	2002/0
	BRS 1	*4335391* PN.	USPA	Ť		2002/0
	BRS 1	*6013553* PN.	USPA"			2002/0
	BRS 1	4199771.pn.	USPA.			2002/0
	BRS 2	(aln or ("al.sub.2 o.sub.3") or (aluminum adj (nitride or oxide))) and "4939571"		T; US-PGPUB		2002/0
	BRS 11	(aln or ("al.sub.2 o.sub.3") or (aluminum adj (nitride or oxide))) with buffer with gate		T: US-PGPUB		2002/0
	BRS 0	(aln or ("al.sub.2 o.sub.3") or (aluminum adj (nitride or oxide))) with blocker with gate		T: US-PGPUB		2002/0
	BRS 0	(aln or ("al <sb>2</sb> o <sb>3</sb> ") or (aluminum adj (nitride or oxide))) with blocker with gate		T: US-PGPUB		2002/0
	BRS 3	(aln or ("al <sb>2</sb> o <sb>3</sb> ") or (aluminum adj (nitride or oxide))) with buffer with gate		JPO: DERWEI	IT: IBM TOE	2002/0
	BRS 12	(("al.sub.2 o.sub.3") or (aluminum adj oxide)) and ((aln) or (aluminum adj nitride)) and (sin or (silicon adj nitri				2002/0
	BRS 9	(("al.sub.2o.sub.3") or ("al.sub.2 o.sub.3") or (aluminum adj oxide)) with ((aln) or (aluminum adj nitride)) with	USPA	T: US-PGPUB		2002/0
32	BRS 0	(("al.sub.2o.sub.3") or ("al.sub.2 o.sub.3") or (aluminum adj oxide)) with ((aln) or (aluminum adj nitride)) with	USPA	T: US-PGPUB		2002/0
	BRS 0	((("al.sub.2o.sub.3") or ("al.sub.2 o.sub.3") or (aluminum adj oxide)) with ((aln) or (aluminum adj nitride)) with				2002/0
	BRS 0	((("al.sub.2o.sub.3") or ("al.sub.2 o.sub.3") or (aluminum adj oxide)) with ((aln) or (aluminum adj nitride)) with	USPA	T: US-PGPUB		2002/0
	BRS 0	((("al.sub.2o.sub.3") or ("al.sub.2 o.sub.3") or (aluminum adj.oxide)) with ((aln) or (aluminum adj.nitride)) with	USPA'	T: US-PGPUB		2002/0
	BRS 0	(nishizawa.in.) and (zaidan.as.) and (aluminum adj (oxide or nitride))		JPO: DERWEI	NT.	2002/0
	BRS 0	(njshizawa in.) and (zaidan.as.) and (aln)		JPO: DERWEI		2002/0
	BRS 0	(nishizawa.in.) and (zaidan.as.) and (al2o3)		JPO: DERWEI		2002/0

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